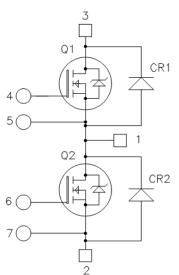
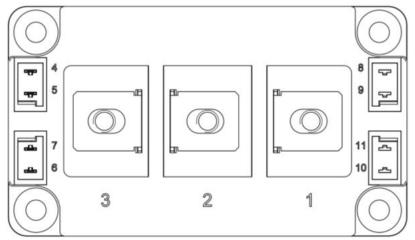


Phase Leg SiC Power Module

Product Overview

The MSCSM170AM039CD3AG device is a 1700 V/523 A phase leg silicon carbide (SiC) power module.





All ratings at T_J = 25 °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM170AM039CD3AG device:

- SiC Power MOSFET
 - Low R_{DS(on)}
 - High temperature performance
- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature Independent switching behavior
 - Positive temperature coefficient on VF
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors
- Aluminum Nitride (AIN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM170AM039CD3AG device:

- High efficiency converter
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS Compliant

Applications

The following are the applications of MSCSM170AM039CD3AG device:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

Electrical Specifications

1. Electrical Specifications

The following sections show the electrical specifications of the MSCSM170AM039CD3AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Symbol Parameter **Maximum Ratings** Unit V_{DSS} Drain-Source voltage 1700 V Continuous drain current T_C = 25 °C 523 А I_D T_C = 80 °C 416 I_{DM} Pulsed drain current 1000 -10/23 V V_{GS} Gate-Source voltage 5 R_{DS(on)} Drain-Source ON resistance mΩ T_C = 25 °C 2400 W Power dissipation P_D

Table 1-1. Absolute Maximum Ratings

The following table lists the electrical characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{DSS}	Zero gate voltage drain current	V _{GS} = 0 V; V _{DS} = 1700 V	V	_	90	900	μA
R _{DS(on)}	Drain-Source on	V _{GS} = 20 V	T _J = 25 °C		3.9	5	mΩ
	resistance	I _D = 270 A	T _J = 175 °C		6.8	_	
V _{GS(th)}	Gate threshold voltage	$V_{GS} = V_{DS}; I_D = 22.5 \text{ m/}$	4	1.8	3.3		V
I _{GSS}	Gate-Source leakage current	V_{GS} = 20 V; V_{DS} = 0 V			_	900	nA

Table 1-2. Electrical Characteristics

Electrical Specifications

The following table lists the dynamic characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
C _{iss}	Input capacitance	V _{GS} = 0 V		-	29.7	—	nF
C _{oss}	Output capacitance	V _{DS} = 1000 V		—	1.3	—	
C _{rss}	Reverse transfer capacitance	f = 1 MHz		_	0.09		
Qg	Total gate charge	V_{GS} = -5 V/20 V		—	1602	_	nC
Q _{gs}	Gate-source charge	V _{Bus} = 850 V		_	441	_	
Q _{gd}	Gate-drain charge	I _D = 270 A		—	243	—	
T _{d(on)}	Turn-on delay time	V_{GS} = -5 V/20 V		_	75	—	ns
Tr	Rise time	V _{Bus} = 900 V		—	75	—	
T _{d(off)}	Turn-off delay time	I _D = 450 A		_	153	_	
T _f	Fall time	T _J = 150 °C R _{GON} = 3.2 Ω R _{GOFF} = 1.8 Ω			56	_	
Eon	Turn-on energy	V _{GS} = -5 V/20 V	T _J = 150 °C	_	20.3	_	mJ
E _{off}	Turn-off energy	V _{Bus} = 900 V I _D = 450 A R _{GON} = 3.2 Ω R _{GOFF} = 1.8 Ω	T _J = 150 °C	_	10.8		mJ
R _{Gint}	Internal gate resistance	e	Э		0.65	_	Ω
R _{thJC}	Junction-to-case therr	nal resistance		—	—	0.063	°C/W

Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Мах	Unit
V_{SD}	Diode forward voltage	V _{GS} = 0 V; I _{SD} = 270 A	_	3.7	—	V
		V_{GS} = -5 V; I _{SD} = 270 A	—	3.9	—	
t _{rr}	Reverse recovery time	I _{SD} = 270 A		27	_	ns
Q _{rr}	Reverse recovery charge	V_{GS} = -5 V		5.9	—	μC
Irr	Reverse recovery current	V _R = 900 V di _F /dt = 9000 A/μs	_	414	—	A

1.2 SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC Schottky diode ratings and characteristics of the MSCSM170AM039CD3AG device.

Symbol	Characteristic	Test Condition	IS	Min	Тур	Max	Unit
V _{RRM}	Peak repetitive reverse voltage	—		-	—	1700	V
I _{RRM}	Reverse leakage current	V _R = 1700 V	T _J = 25 °C	_	70	1400	μA
			T _J = 175 °C	_	1050	—	
I _F	DC forward current	—	T _C = 125 °C	_	210	—	A
V _F	Diode forward voltage	I _F = 210 A	T _J = 25 °C	_	1.5	1.8	V
			T _J = 175 °C	_	2.3	—	
Q _C	Total capacitive charge	V _R = 900 V		_	1610	—	nC
С	Total capacitance	f = 1 MHz, V _R =	= 600 V		1169	—	pF
		f = 1 MHz, V _R =	= 900 V	_	966	_	
R _{thJC}	Junction-to-case thermal re	sistance		—	_	0.09	°C/W

1.3 Thermal and Package Characteristics

The following table lists the package characteristics of the MSCSM170AM039CD3AG device.

Table 1-6. Thermal and Package Characteristics

Symbol	Characteristic	Characteristic			Max	Unit
V _{ISOL}	RMS isolation voltage, any terminal to ca	se t = 1 min, 5	0 Hz/60 Hz	4000	—	V
TJ	Operating junction temperature range			-40	175	°C
T _{JOP}	Recommended junction temperature und	er switching co	onditions	-40	T _{Jmax} –25	
T _{STG}	Storage case temperature			-40	125	
T _C	Operating case temperature			-40	125	
Torque	Mounting torque	For terminals	M6	3	5	N.m
		To heatsink	M6	3	5	
Wt	Package weight			_	350	g

Electrical Specifications

1.4 Typical SiC MOSFET Performance Curve

The following figures show the SiC MOSFET performance curves of the MSCSM170AM039CD3AG device.

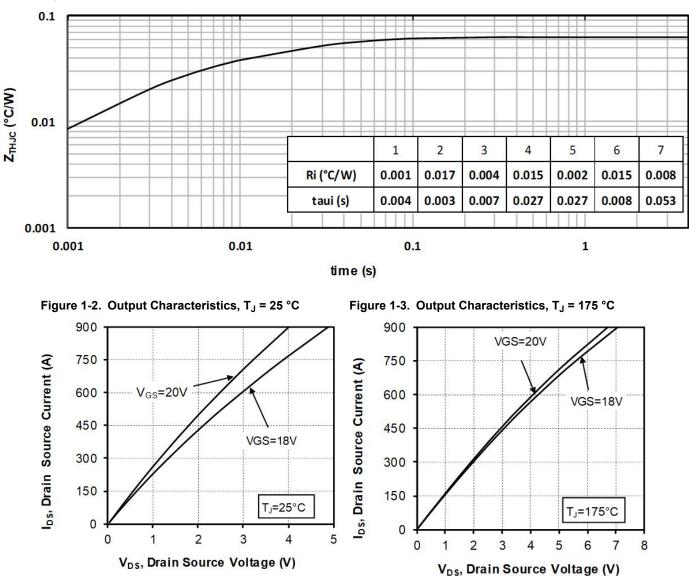
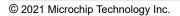


Figure 1-1. Maximum Thermal Impedance



Electrical Specifications

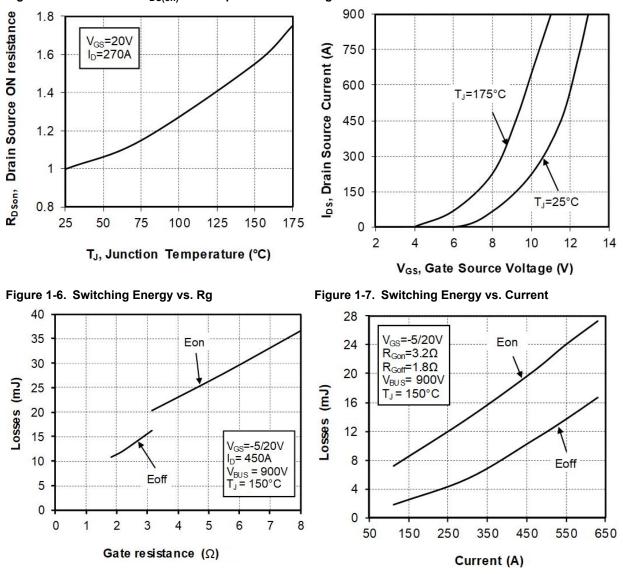
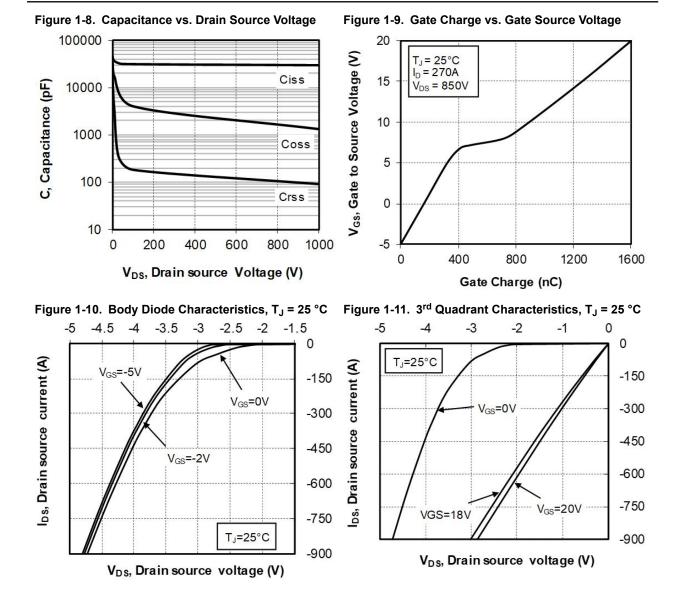


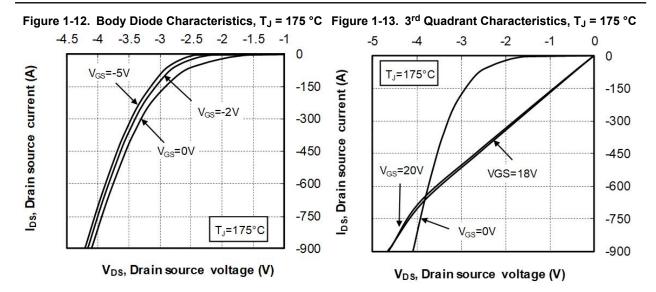
Figure 1-4. Normalized R_{DS(on)} vs. Temperature

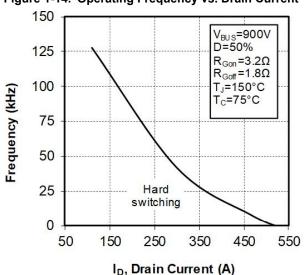
Figure 1-5. Transfer Characteristics

Electrical Specifications



Electrical Specifications







Electrical Specifications

1.5 Typical SiC Diode Performance Curve

The following figures show the SiC diode performance curves of the MSCSM170AM039CD3AG device.

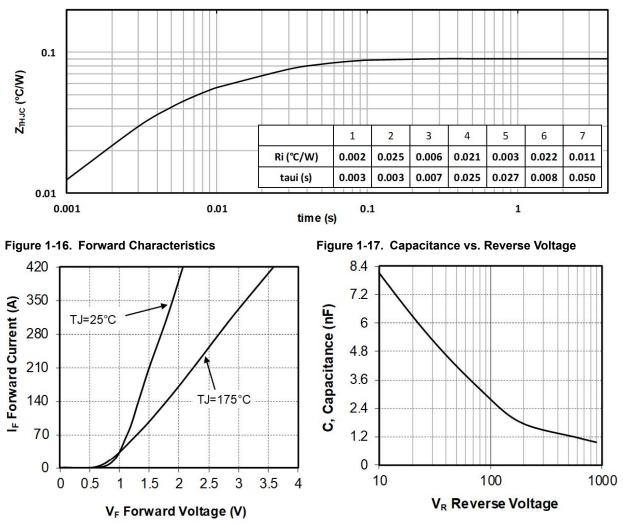


Figure 1-15. Maximum Thermal Impedance

Package Specifications

2. Package Specifications

The following section shows the package specification of the MSCSM170AM039CD3AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM170AM039CD3AG device. The dimensions in the following figure are in millimeters.

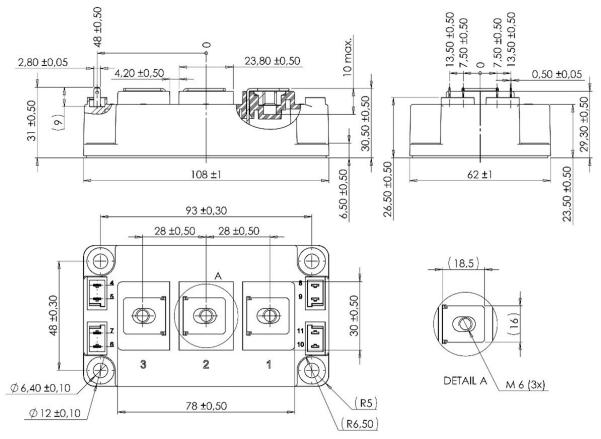


Figure 2-1. Package Outline Drawing

Note: See application note 1908—Mounting instructions for D3 and D4 power modules for more information.

3. Revision History

Revision	Date	Description
A	04/2021	This is the first publication of this document.

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